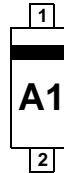


BAS16HT1G

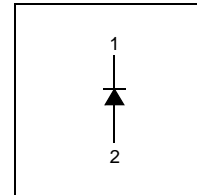
Small Signal Diode



SOD-323



Connection Diagram



Absolute Maximum Ratings * $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{RRM}	Maximum Repetitive Reverse Voltage	85	V
$I_{F(AV)}$	Average Rectified Forward Current	200	mA
I_{FSM}	Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 second	600	mA
T_{STG}	Storage Temperature Range	-65 to +150	$^\circ\text{C}$
T_J	Operating Junction Temperature	-55 to +150	$^\circ\text{C}$

* These ratings are limiting values above which the serviceability of the diode may be impaired.

NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

Symbol	Parameter	Value	Units
P_D	Power Dissipation	200	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	600	$^\circ\text{C/W}$

Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Max.	Units
V_R	Breakdown Voltage	$I_R = 5.0\mu\text{A}$	85		V
V_F	Forward Voltage	$I_F = 0.1\text{mA}$ $I_F = 10\text{mA}$ $I_F = 50\text{mA}$ $I_F = 150\text{mA}$		715 855 1.0 1.25	mV mV V V
I_R	Reverse Leakage	$V_R = 75\text{V}$ $V_R = 25\text{V}, T_A = 150^\circ\text{C}$ $V_R = 75\text{V}, T_A = 150^\circ\text{C}$		1.0 30 50	μA μA μA
C_T	Total Capacitance	$V_R = 0, f = 1.0\text{MHz}$		2.0	pF
t_{rr}	Reverse Recovery Time	$I_F = I_R = 10\text{mA}, I_{RR} = 1.0\text{mA}, R_L = 100\Omega$		6.0	ns

Typical Performance Characteristics

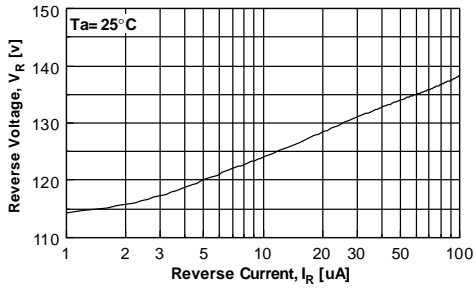


Figure 1. Reverse Voltage vs Reverse Current
BV - 1.0 to 100 μ A

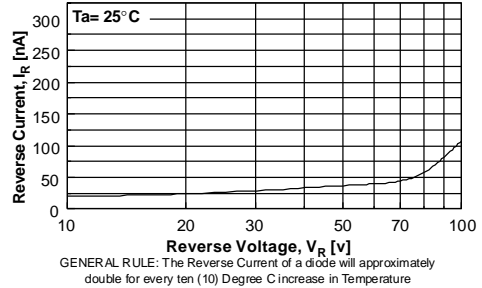


Figure 2. Reverse Current vs Reverse Voltage
IR - 10 to 100V

GENERAL RULE: The Reverse Current of a diode will approximately double for every ten (10) Degree C increase in Temperature

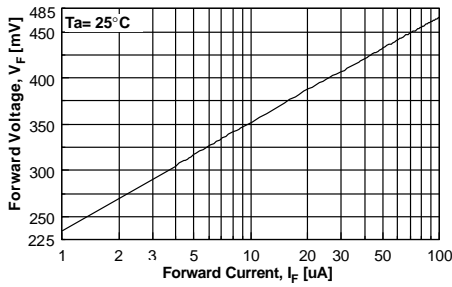


Figure 3. Forward Voltage vs Forward Current
VF - 1.0 to 100 μ A

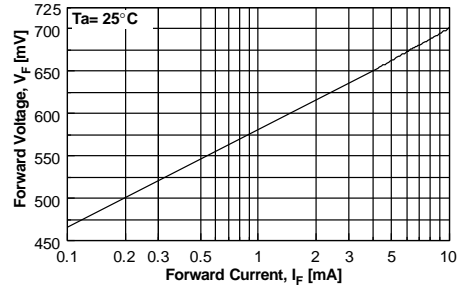


Figure 4. Forward Voltage vs Forward Current
VF - 0.1 to 10mA

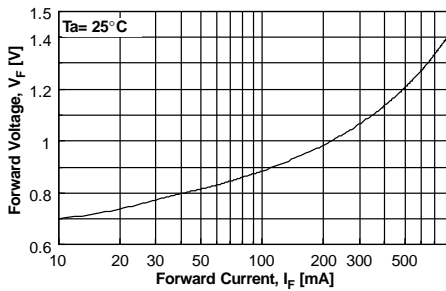


Figure 5. Forward Voltage vs Forward Current
VF - 10 - 800mA

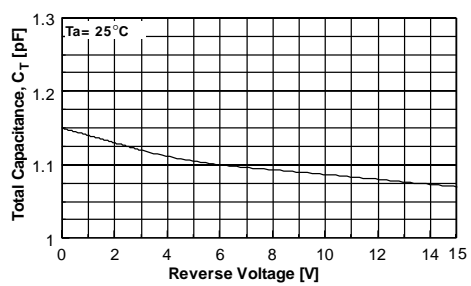


Figure 6. Total Capacitance

Typical Performance Characteristics (Continued)

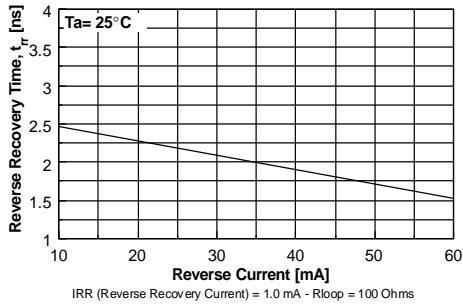


Figure 1. Reverse Recovery Time vs Reverse Current
TRR - IR 10mA vs 60mA

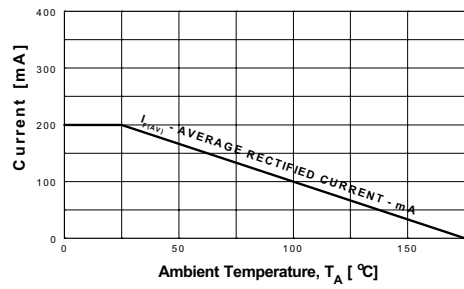


Figure 2. Average Rectified Current ($I_{F(AV)}$) vs
Ambient Temperature (T_A)

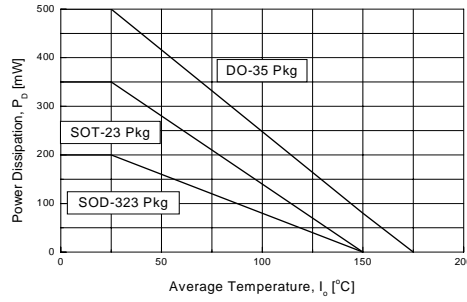
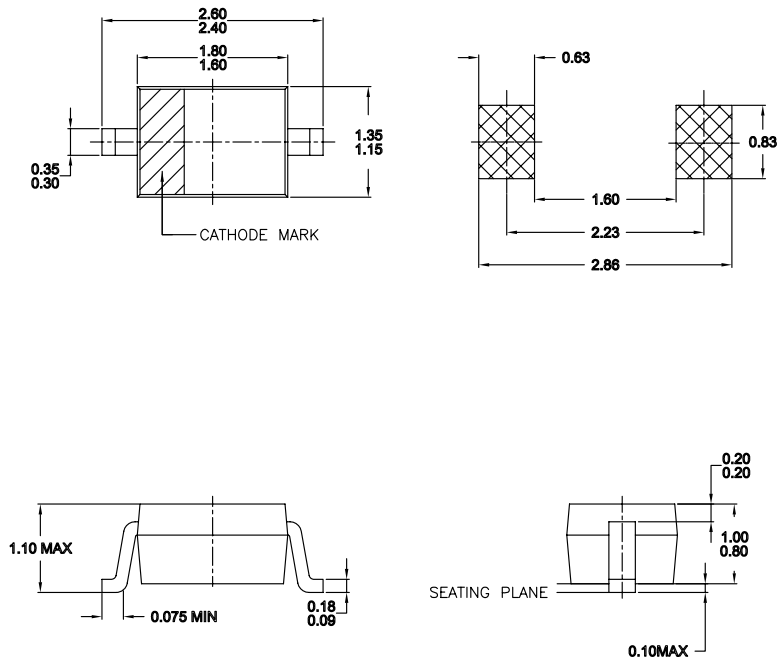


Figure 3. Power Derating Curve

Physical Dimension

SOD-323







NOTES: UNLESS OTHERWISE SPECIFIED
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 B) ALL DIMENSIONS ARE IN MILLIMETERS.
 C) DIMENSIONS ARE EXCLUSIVE OF BURRS,
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 D) DIMENSIONS AND TOLERANCES PER
 ASME Y14.5M-1994

Dimensions in Millimeters



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